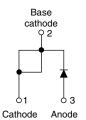


VS-20TQ0..PbF Series, VS-20TQ0..-N3

Vishay Semiconductors

Schottky Rectifier, 20 A





PRODUCT SUMMARY								
Package	TO-220AC							
I _{F(AV)}	20 A							
V _R	35 V, 40 V, 45 V							
V_F at I_F	0.51 V							
I _{RM} max.	105 mA at 125 °C							
TJ	150 °C							
Diode variation	Single die							
E _{AS}	27 mJ							

FEATURES

- 150 °C T_J operation
- Low forward voltage drop
- High frequency operation



RoHS

- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
 - COMPLIANT HALOGEN long
- Guard ring for enhanced ruggedness and long term reliability
- Compliant to RoHS Directive 2002/95/EC
- Designed and qualified according to JEDEC-JESD47
- Halogen-free according to IEC 61249-2-21 definition (-N3 only)

DESCRIPTION

The VS-20TQ... Schottky rectifier series has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 150 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
I _{F(AV)}	Rectangular waveform	20	А							
V _{RRM}	Range	35 to 45	V							
I _{FSM}	t _p = 5 μs sine	1800	А							
V _F	20 A _{pk} , T _J = 125 °C	0.51	V							
TJ	Range	- 55 to 150	°C							

VOLTAGE RATINGS											
PARAMETER	SYMBOL	VS- 20TQ035PbF	VS- 20TQ035-N3	VS- 20TQ040PbF	VS- 20TQ040-N3	VS- 20TQ045PbF	VS- 20TQ045-N3	UNITS			
Maximum DC reverse voltage	V _R										
Maximum working peak reverse voltage	V _{RWM}	35	35	40	40	45	45	V			

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST COND	VALUES	UNITS						
Maximum average forward current See fig. 5	I _{F(AV)}	$I_{F(AV)}$ 50 % duty cycle at T _C = 116 °C, rectangular waveform								
Maximum peak one cycle non-repetitive surge current	I _{ESM}	5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1800	А					
See fig. 7	IFSM	10 ms sine or 6 ms rect. pulse	V_{RRM} applied	400						
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 \text{ °C}, I_{AS} = 4 \text{ A}, L = 3.4 \text{ m}$	27	mJ						
Repetitive avalanche current	I _{AR}	Current decaying linearly to zer Frequency limited by T _J maxim	4	А						

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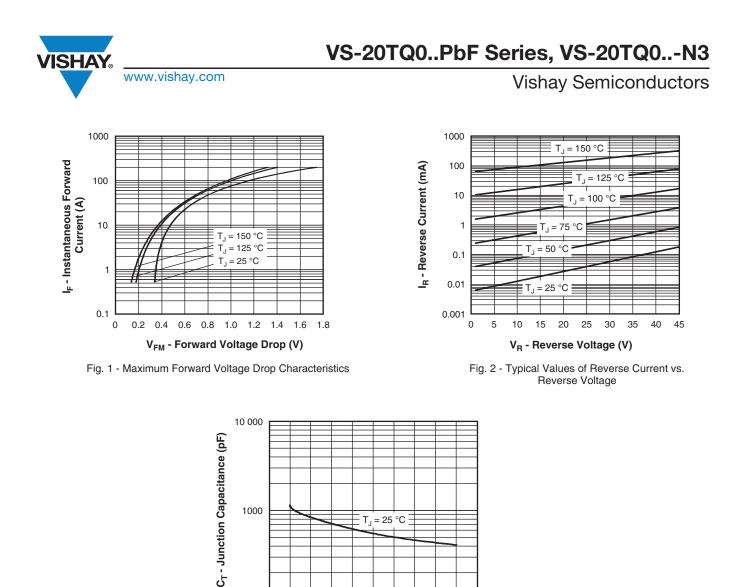
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ELECTRICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS						
Maximum forward voltage drop See fig. 1		20 A	T.I = 25 °C	0.57						
	V _{FM} ⁽¹⁾	40 A	1] = 25 0	0.73	V					
		20 A	T.I = 125 °C	0.51	v					
		40 A	1j = 125 C	0.67						
Maximum reverse leakage curent	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B}$ = Rated V _B	2.7	mA					
See fig. 2	IRM \''	T _J = 125 °C	V _R = naleu V _R	105						
Maximum junction capacitance	CT	$V_R = 5 V_{DC}$, (test signal ran	1400	pF						
Typical series inductance	Ls	Measured lead to lead 5 m	8.0	nH						
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs					

Note

 $^{(1)}\,$ Pulse width < 300 $\mu s,$ duty cycle < 2 $\,\%$

THERMAL - MECHANICAL SPECIFICATIONS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Maximum junction and storage temperature range	T _J , T _{Stg}		- 55 to 150	°C						
Maximum thermal resistance, junction to case	R _{thJC}	DC operation See fig. 4	1.50	°C/W						
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth and greased	0.50	0/11						
Approximate weight			2	g						
Approximate weight			0.07	oz.						
Mounting torque			6 (5)	kgf · cm						
Mounting torque maximum			12 (10)	(lbf · in)						
			20T0	Q035						
Marking device		Case style TO-220AC	20TQ040							
			20TQ045							



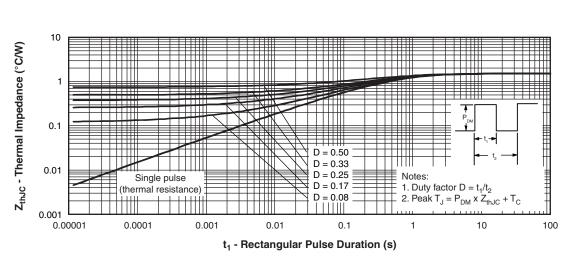
T_{.1} = 25 °C

30

V_R - Reverse Voltage (V) Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

40

50



100 0

10

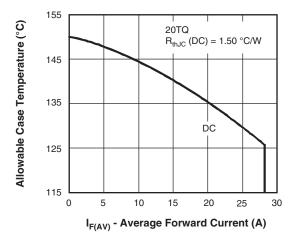
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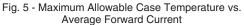


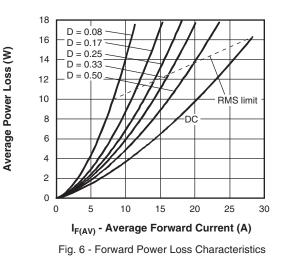


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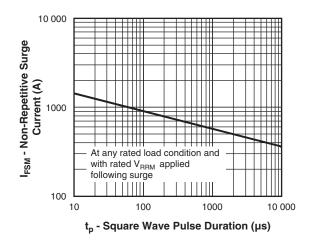


Fig. 7 - Maximum Non-Repetitive Surge Current

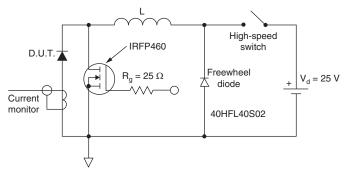


Fig. 8 - Unclamped Inductive Test Circuit

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ORDERING INFORMATION TABLE

Device

code	VS-	20	т	Q	045	PbF
		2	3	4	5	6
	1	- Vis	hay Sen	niconduo	ctors pro	oduct
	2 - 3 -		rent ratii kage:	ng (20 =	20 A)	
		-	TO-220			
	4 - 5 -		ottky "Q tage rati			
	6 -		vironmer	0		
		• F	PbF = Le	ad (Pb)·	-free and	d RoHS
		• -	N3 = Ha	logen-fr	ee, RoH	IS comp

ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-20TQ035PbF	50	1000	Antistatic plastic tube							
VS-20TQ035-N3	50	1000	Antistatic plastic tube							
VS-20TQ040PbF	50	1000	Antistatic plastic tube							
VS-20TQ040-N3	50	1000	Antistatic plastic tube							
VS-20TQ045PbF	50	1000	Antistatic plastic tube							
VS-20TQ045-N3	50	1000	Antistatic plastic tube							

LINKS TO RELATED DOCUMENTS						
Dimensions		www.vishay.com/doc?95221				
Part marking information	TO-220AC PbF	www.vishay.com/doc?95224				
	TO-220AC -N3	www.vishay.com/doc?95068				



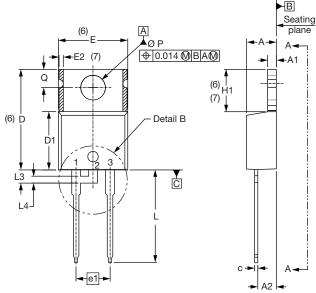
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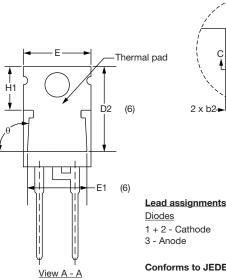
TO-220AC

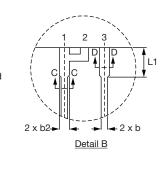
plane

A-

DIMENSIONS in millimeters and inches









Diodes 1 + 2 - Cathode 3 - Anode

Conforms to JEDEC outline TO-220AC

⊕ 0.015 **()** BA()

SYMBOL	MILLIM	IETERS	INCHES		NOTES	SYMBOL	MILLIMETERS		INCHES		NOTES	
STNIDOL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183			E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055			E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115			е	2.41	2.67	0.095	0.105	
b	0.69	1.01	0.027	0.040			e1	4.88	5.28	0.192	0.208	
b1	0.38	0.97	0.015	0.038	4		H1	6.09	6.48	0.240	0.255	6, 7
b2	1.20	1.73	0.047	0.068			L	13.52	14.02	0.532	0.552	
b3	1.14	1.73	0.045	0.068	4		L1	3.32	3.82	0.131	0.150	2
с	0.36	0.61	0.014	0.024			L3	1.78	2.13	0.070	0.084	
c1	0.36	0.56	0.014	0.022	4		L4	0.76	1.27	0.030	0.050	2
D	14.85	15.25	0.585	0.600	3		ØΡ	3.54	3.73	0.139	0.147	
D1	8.38	9.02	0.330	0.355			Q	2.60	3.00	0.102	0.118	
D2	11.68	12.88	0.460	0.507	6		θ	90° t	o 93°	90° t	o 93°	
E	10.11	10.51	0.398	0.414	3, 6							

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

- ⁽²⁾ Lead dimension and finish uncontrolled in L1
- (3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimension: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1
- ⁽⁷⁾ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed
- ⁽⁸⁾ Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline



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